

December 2000

DESCRIPTION

The 73M2901/3.3V is a single-chip modem that combines all the controller (DTE) and data pump functions necessary to implement an intelligent V.22bis data modem. This device is based on TDK Semiconductor's implementation of the industry standard 8032 microcontroller core with a proprietary multiply and accumulate (MAC) coprocessor; Sigma-Delta A/D and D/A converters; and an analog front end. The ROM and RAM necessary to operate the modem are contained on the device. Additionally, the 73M2901/3.3V provides an on-chip oscillator and Hybrid driver.

The 73M2901/3.3V is a high performance, low voltage, low power, single chip modem capable of data transmission and reception through 2400bps. The 73M2901/3.3V is intended for embedded applications and battery operation. This device offers low power 3.3 volt design with optional internal hybrid and country specific call progress support.

FEATURES

- Low overall system chip count. True one chip solution for embedded systems
- Low operating power (~120mW @ 3.3V, automatic low power standby and power down options available)
- Internal ROM and RAM for normal operation
- On chip optional hybrid driver
- Designed for +3.15 through +3.6 volts
- Data speeds:

V.22bis - 2400bps

V.22, Bell 212 - 1200bps

V.21, Bell 103 - 300bps

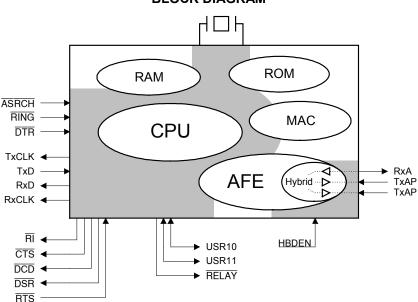
V.23 – 1200/75bps (w/ turnaround (PAVI))

Bell 202 - 1200bps

Bell 202 and V23 4-wire operations

- Dynamic Range: -9dBm to -43 dBm
- "AT" command set
- Host access to modem port pins via AT commands for custom I/O expansion
- DTMF tone generation and detection
- Call progress support with multinational options (FCC68, CTR21, JATE...)
- Caller ID capability
- · Blacklisting capability
- Packaging: 32 pin PLCC or 44 pin TQFP

BLOCK DIAGRAM



HARDWARE DESCRIPTION

The 73M2901/3.3V is designed for a single +3.3 volt supply with low power consumption (~120mW @ 3.3 volts). The modem supports automatic standby idle mode. The modem will also accept a request to power down from the DTE via hardware control. No additional major components are required to complete the modem core logic. The modem provides direct firmware LED support via port pins.

HARDWARE FEATURES

- Fully self-contained. "AT" Command interpreter and data pump
- User pin available
- Synchronous serial data I/O available
- Asynchronous serial port
- On-chip hybrid driver.
- Autobaud capability from 300bps to 9600bps

POWER SUPPLY

Power is supplied to the 73M2901/3.3V via the VPD and VPA pins. The 73M2901/3.3V is designed for a single +3.15 through +3.6 volt supply and for low power consumption (~120mW @ 3.3 volts). Ground Reference is provided at the VND and VNA pins.

LOW POWER MODE

The TDK 73M2901/3.3V supports a low power mode. If the low power standby option is enabled the 73M2901/3.3V will go into a power saving mode when idle. The oscillator will be running, clocks will be supplied to the UART, timers and interrupt blocks; but no clocks will be supplied to the CPU. Instruction processing and activity on the internal busses is halted. Normal operation is resumed when an interruption such as $\overline{\rm DTR}$, $\overline{\rm RING}$ or $\overline{\rm ASRCH}$ (any character send to the 73M2901/3.3V) is requested or when a reset occurs.

ANALOG LINE / HYBRID INTERFACE

The 73M2901/3.3V provides a differential analog output (TXAP and TXAN) and a single-ended analog input (RXA) with internal A/D and D/A converters. A driver is provided for an internal hybrid function.

The internal hybrid driver is capable of driving an external load matching impedance and a line-coupling transformer. If an external hybrid is to be used, the on-chip hybrid drivers can be reconfigured to drive a minimum load of $50k\Omega$ and thus reduce the driver's power consumption.

The hybrid configuration is controlled by the state of the HBDEN pin. For driving a line-coupling transformer, HBDEN should be pulled high. For driving an external hybrid (load on TXAP and TXAN is $50k\Omega$ or larger), HBDEN should be pulled low.

The 73M2901/3.3V provides firmware control for a hook relay driver (RELAY) as well as interrupt support for a ring detect opto-coupler (RING).

INTERRUPT PINS

The external interrupt sources, \overline{DTR} , \overline{ASRCH} and \overline{RING} , come from dedicated input pins of the same name.

DTR informs the 73M2901/3.3V that the host has requested the 73M2901/3.3V perform a specific function. The actual particulars of that function can be changed by "AT" commands (described in full in the TDK 73M2901 User's Guide).

ASRCH informs the 73M2901/3.3V that the host is passing data to the 73M2901/3.3V over the DTE interface. This instructs the 73M2901/3.3V to begin looking for valid "AT" commands. This pin needs to be connected to the TXD pin.

RING informs the 73M2901/3.3V that the external DAA circuitry has detected a ring signal.

CRYSTAL OSCILATOR

The TDK 73M2901/3.3V single chip modem can use an external 11.0592 MHz reference clock or can generate such a clock using only a crystal and two capacitors. If an external clock is used, it should be applied to OSCIN.

SPECIFYING A CRYSTAL

The manufacturer of a crystal resonator verifies its frequency of oscillation in a test set-up, but to ensure that the same frequency is obtained in the application, the circuit conditions must be the same. The TDK 73M2901/3.3V modem requires a parallel mode (antiresonant) crystal, the important specifications of which are as follows:

Mode: Parallel (antiresonant)

Frequency: 11.0592 MHz

Frequency tolerance: ±50 ppm at initial

temperature.

Temperature drift: ±50 ppm additional over full

Range.

Load capacitance: 18pF or 20pF ESR: 75Ω max.

Drive level: Less than 1mW.

RESET

A reset is accomplished by holding the RESET pin high. To ensure a proper power-on reset, the reset pin must be held high for a minimum of $3\mu s$. At power on, the voltage at VPD, VPA, and RESET must come up at the same time for a proper reset.

ASYNCHRONOUS AND SYNCHRONOUS SERIAL DATA INTERFACE

The serial data interface consists of the TXD and RXD data paths (LSBit shifted in and out first, respectively); and the TXCLK and RXCLK serial clock outputs associated with the data pins; $\overline{\text{CTS/RTS}}$ flow control; $\overline{\text{DCR}}$, $\overline{\text{DSR}}$ and $\overline{\text{DTR}}$. In synchronous mode, the data is passed at the bit rate (tolerance is +1%, -2.5%).

PIN DESCRIPTIONS

POWER PIN DESCRIPTION

PIN NAME	32-PIN	44-PIN	TYPE	DESCRIPTION
VPA	15	16	I	Positive analog voltage (+ Analog Supply)
VNA	21	22	I	Negative analog voltage. (Analog Ground)
VPD	6, 25, 29	2,12, 27, 33	I	Positive digital voltage (+ Digital Supply)
VND	5, 22, 26	11, 24, 44, 28	I	Negative digital voltage. (Digital Ground)

ANALOG INTERFACE PIN DESCRIPTION

PIN NAME	32-PIN	44-PIN	TYPE	DESCRIPTION
RXA	20	21	I	Receive analog data
TXAN	16	17	0	Transmit Analog -
TXAP	17	18	0	Transmit Analog +
HBDEN	14	15	I	2w/4w hybrid driver enable pin
				0 = Driver configured for $50k\Omega$ or greater load (Tie to VND) 1 = Driver configured for driving line-coupling transformer (Tie to VPD)
VBG	19	20	0	Analog Band Gap voltage reference pin (0.1µF to VNA)
VREF	18	19	0	Analog reference voltage pin (0.1µF to VNA)

EXTERNAL INTERRUPTS PIN DESCRIPTIONS

PIN NAME	32-PIN	44-PIN	TYPE	DESCRIPTION
RING	2	39	I	External interrupt – Line interface ring detection circuitry input
ASRCH	1	38	I	External interrupt – Autobaud detection, connected to TXD
DTR	32	37	I	External interrupt – DTE DTR signal input

PIN DESCRIPTIONS (continued)

OSCILLATOR PIN DESCRIPTION

PIN NAME	32-PIN	44-PIN	TYPE	DESCRIPTION
OSCIN	24	26	I	Crystal input for internal oscillator, also input for external source.
OSCOUT	23	25	0	Crystal oscillator output.

DIGITAL INTERFACE PIN DESCRIPTION

PIN NAME	32-PIN	44-PIN	TYPE	DESCRIPTION
RESET	13	9	I	Resets 73M2901/3.3V
RXCLK	31	36	0	Receive Data Synchronous Clock
RXD	30	35	0	Serial output to DTE.
TXCLK	28	31	0	Transmit Data Synchronous Clock
TXD	27	30	I	Serial data input from DTE.
USR10	12	8	I/O	This pin can optionally be configured as an active low detect pin. This can be used to implement such functions as "parallel-pick-up", "line-in-use", or "seize" detect.
USR11	11	7	I/O	Programmable I/O port. This pin can ooptionnaly be used to control an external switch for Caller ID decoding operations.
RTS (USR12)	10	6	I	Request to Send
CTS (USR13)	9	5	0	Clear to Send
DSR (USR14)	8	4	0	Data Set Ready
DCD (USR15)	7	3	0	Data Carrier Detect
RI (USR16)	4	43	0	Ring Indicator
RELAY (USR17)	3	40	0	Relay driver output

ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

Operation above maximum rating may permanently damage the device.

PARAMETER	RATING
Supply Voltage	-0.5V to +7.0V
Pin Input Voltage	-0.5V to VPD + 0.5V
Storage Temperature	-55°C to 150°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	RATING
Supply Voltage	3.15V – 3.6V
Oscillator Frequency	11.0592MHz +/- 50ppm
Operating Temperature	-40C to +85°C

TRANSMITTER

PARAMETER	CONDITIONS	MIN	NOM	MAX	UNIT
ITU Guard Tone Power	550Hz (relative to carrier)	-5	-3.5	-2	dB
	1800Hz (relative to carrier)	-8	-6.5	-5	dB
Calling Tone	1300Hz	-11		-9.0	dBm0 ¹
Answer Tone Power	2225/2100Hz	-11		-9.0	dBm0 ¹
DTMF Transmit Power	High band tones	-8.0		-6.0	dBm0 ¹
	Low band tones	-10		-8.0	

MAXIMUM TRANSMIT LEVELS					
Vref =1.25V; VPA = 3.3V					
QAM	-9.6				
DPSK	-7.4				
FSK	-5.3				
DTMF (high tone)	-7.9				
DTMF (low tone)	-9.8				
DTMF (total)	-5.7				

Note: The recommended DAA (see the TDK 73M2901 Reference Manual) will result in approximately 8dB loss from the transmit pins to the phone line. This includes the loss through the line matching impedance (475Ω resistor), transformer, and solid state off-hook relay.

 $^{^{1}}$ dBm0 refers to the TDK recommended DAA (8dB loss from Transmit pins to the line and 5dB loss from the line to the Receive pin). Results may vary depending on selected DAA. 0dBm = 0.775V_{rms}. dBm = 10log {Vrms}²/[(1mW)(600Ω)]}

ELECTRICAL SPECIFICATIONS (continued)

TRANSMITTER

PARAMETER	CONDITIONS	MIN	NOM	MAX	UNIT
Gain Adjust Tolerance	By step	-0.3	0	0.3	dB
Total Harmonic Distortion (THD)	1Khz sine wave at output (TXAP-TXAN) 1.5Vpk(2.7dBm) for Vref=1.25V THD = 2 nd and 3 rd harmonic.			-50	dB
Intermod Distortion	At output (TXAP-TXAN) 1.0kHz, 1.2 kHz sine waves summed 2.0Vpk for Vref=1.25V	freq	each unwanted frequency component		dB
	Refer to CTR21 specification for complete description of requirements	sum of unwanted frequency components in pass band		-20	dB below low tone
Power Supply Rejection Ratio	-30 dBm signal at VPA 300Hz – 30kHz. Measured TXAP to TXAN.			30.0	dB

RECEIVER

PARAMETER	CONDITIONS	MIN	NOM	MAX	UNIT
Carrier Detect On	Tip and Ring	-43.0			dBm0 ¹
Carrier Detect Off	Tip and Ring	-48.0			dBm0 ¹
Carrier Detect Hysteresis	Tip and Ring		2.0		dB
Receive Level	Tip and Ring	-43.0		-9.0	dBm0 ¹
Idle Channel Noise	0.2kHz - 4.0kHz		-70	-65	dB

ELECTRICAL SPECIFICATIONS (continued)

RECEIVER (continued)

PARAMETER	TEST CONDITION	MIN	NOM	MAX	UNITS
Input Impedance	RXA	150			kΩ
Receive Gain Boost	SFR 96h bit 2 (Rxgain) = 1	2.7	3.0	3.3	dB
Maximum Input Level at RXA	VREF=1.25V			0.587	Vpk
Total Harmonic Distortion (THD)	1kHz 450mV-pk on RXA THD = 2 nd and 3 rd harmonic.		-70	-50	dB

DC CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN	NOM	MAX	UNIT
Input Low Voltage (Except OSCIN,RESET)	VIL		-0.5		0.2Vcc	V
Input Low Voltage OSCIN,RESET	VIL		-0.5		0.2 Vcc	V
Input High Voltage (Except OSCIN,RESET)	VIH		0.5 Vcc		Vcc + 0.5	V
Input High Voltage OSCIN,RESET	VIH		0.7 Vcc		Vcc + 0.5	V
Output Low Voltage (Except OSCOUT)	VOL	IOL = 4mA			0.45	V
Output Low Voltage OSCOUT	VOLOSC	IOL = 3.0mA			0.7	V
Output High Voltage (Except OSCOUT)	VOH	IOH = -4mA	Vcc - 0.45			V
Output High Voltage OSCOUT	VOHOSC	IOH =-3.0mA	Vcc – 0.9			V
Input Leakage Current (Except OSCIN)	IIH	Vss < Vin < Vcc			1	μА
Input Leakage Current OSCIN	IIH	Vss < Vin < Vcc	1		30	μА

ELECTRICAL SPECIFICATIONS (continued)

DC CHARACTERISTICS

PARAMETER	SYMBOL	CONDITION	MIN	NOM	MAX	UNIT
3.3V Operations						
Maximum Power Supply Normal Operation @ 3.3V HBDEN pulled high	IDD1	30pF/pin		37	46	mA
Maximum Power Supply Normal Operation @ 3.3V HBDEN pulled low	IDD1	30pF/pin		22	28	mA
Maximum Digital Power Supply @ 3.3V	IDDd	30pF/pin		19	23	mA
Maximum Analog Power Supply @ 3.3V HBDEN pulled high	IDDah1	30pF/pin		18	23	mA
Maximum Analog Power Supply @ 3.3V HBDEN pulled low	IDDah0	30pF/pin		3	5	mA
Maximum Power Supply Idle Mode @ 3.3V	IDD2	30pF/pin		7	9	mA
Maximum Power Supply Power Down Mode @ 3.3V	IDD3	30pF/pin		3	5	μА

PARAMETER	CONDITION	MIN	NOM	MAX	UNIT
Vbg	Vcc=3.3V	1.19	1.25	1.31	V
Vref	Vcc=3.3V	1.19	1.25	1.31	V

NOTE

The TDK 73M2901/3.3V is also tested and suitable for operations at 5 volt supply. Please refer to the 73M2901/5V Data Sheet for details.

FIRMWARE DESCRIPTION²

An "AT" command interpreter provides command and configuration of the 73M2901/3.3V. This provides the user a uniform interface to control the modem in embedded applications.

The signal processing is performed by obtaining data from and providing data to the integrated A/D converter. A MAC hardware processor is provided for computation.

To provide maximum flexibility, the system host processor can access the internal RAM and Control Register space in the modem. This will allow the OEM user to modify parameters such as filter response, transmit levels through the AT command set using proprietary commands. The host processor can also access the modem I/O port pins, providing extended I/O capability.

FIRMWARE REQUIREMENTS

The modem always powers up in the idle (on hook) mode. "AT" commands are issued via the serial interface from the host. All modem configuration commands are received in this manner. The data modem firmware is contained in an internal ROM. The firmware will automatically enter a power saving idle mode if the modem is on hook and there are no incoming host commands. The modem automatically powers up upon receiving the next command. This power up sequence occurs without delay to the host. This function, while saving power, is transparent to the host processor and can be disabled by the host via an "AT" command. The host can also program the modem to power down via external pin (DTR) or via a firmware command.

FIRMWARE FEATURES

- "AT" command set
- Supports data standards through V.22bis
- Provides DAA control firmware (e.g. ring detect, hook control, line in use detection support)
- Multinational Call progress support (FCC68, CTR21, JATE...)
- Caller ID capability
 FSK demodulation (V23 or Bell202)
 Intra 1st/2nd ring CID data operations
 Post Line reversal CID data operations
- Interfaces with standard V.24/EIA-232 (3-5 volt inverted level) serial interface using the built in serial port and firmware control of port pins
- Provides tone generation and detection, four imprecise and four precise call progress detect filters
- Host access to program RAM provided
- User access to modem functions

² For a detailed description of the firmware consult the TDK 73M2901 User's Manual.

DESIGN CONSIDERATIONS

TDK Semiconductor's single chip modem solutions include all the basic modem functions. This makes these devices adaptable to a variety of applications.

Unlike digital logic circuitry, modem designs must contend with precise frequency tolerances and verify low level analog signals, to ensure acceptable performance. Using good analog circuit design practices will generally result in a sound design. The crystal oscillator should be held to a 50ppm tolerance. Following are additional recommendations that should be taken into consideration when starting new designs.

LAYOUT CONSIDERATIONS

Good analog/digital design rules must be used to control system noise in order to obtain high performance in modem designs. The more digital circuitry present in the application, the more attention to noise control is needed.

High speed, digital devices should be locally bypassed, and the telephone line interface and the modem should be located next to each other near where the telephone line connection is accessed. It is recommended that power supplies and ground traces should be routed separately to the analog and digital portions on the board. Digital signals should not be routed near low level analog or high impedance analog traces.

The 73M2901/3.3V should be considered a high performance analog device. A $10\mu F$ electrolytic capacitor in parallel with a $0.1\mu F$ Ceramic capacitor should be placed between VPD and VND as well as between VPA and VNA. A $0.1\mu F$ ceramic capacitor should be placed between VREF and VNA as well as VBG and VNA. Use of ground planes and large traces on power is recommended.

The 73M2901/3.3V is the first of a series of parts with different and/or additional features. In order to insure full lay out compatibility for all the series, it is recommended to implement three additional resistors in the schematics as shown in the recommended schematics arrangement (R11, R12 and R13).

TELEPHONE LINE INTERFACE

Transmit levels at the line are dependent on the interface used between the pins and the line. In order to save having to provide external op-amps to drive the line coupling transformer, the analog outputs (TXAP and TXAN) have the capability to be used as the hybrid drivers for connecting to the

transformer directly (with the required impedance matching series resistor). Used in this configuration, there is loss associated in both the receive path and transmit path.

The line interface circuit shown on the following page represents the basic components and values for interfacing the TDK 73M2901/3.3V analog pins to the telephone line.

MODEM PERFORMANCE CHARACTERISTICS

The curves presented in this data sheet define modem IC performance under a variety of line conditions typical of those encountered over public service telephone lines.

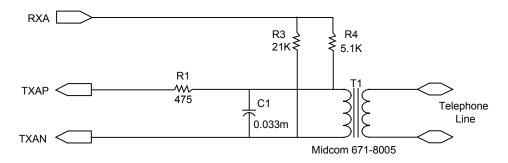
BER VS. SNR

This test represents the ability of the modem to operate over noisy lines with a minimum amount of data transfer errors. Since some noise is generated in the best dial up lines, the modem must operate with the lowest signal to noise ratio (SNR) possible. Better modem performance is indicated by test curves that are closest to the BER axis. A narrow spread between curves representing the four line indicates minimal parameters variation performance while operating over a range of aberrant operating conditions. Typically a DPSK modem will exhibit better BER performance test curves receiving in the low band (answer mode) than in the high band (originate mode).

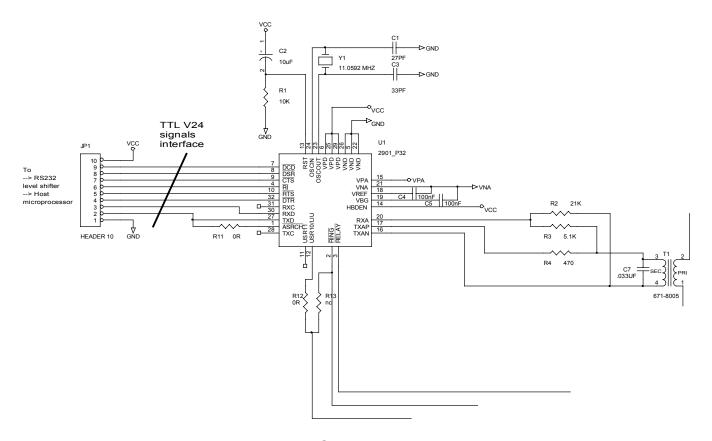
BER VS. RECEIVE LEVEL

This test measures the dynamic range of the modem. Because signal levels vary widely over dial up lines, the widest possible dynamic range is desirable. The SNR is held constant at the indicated values as the Receive level is lowered from very a very high to a very low signal level. The width of the bowl of these curves, taken at the BER point is the measure of the dynamic range.

³ TDK73M2901 Demo boards use the line interface shown on the following page. Other designs may have different requirements and thus will require different component values or a different configuration. With the shown configuration, there is approximately an 8dB loss in the transmit path, and approximately a 5dB loss in the receive path.

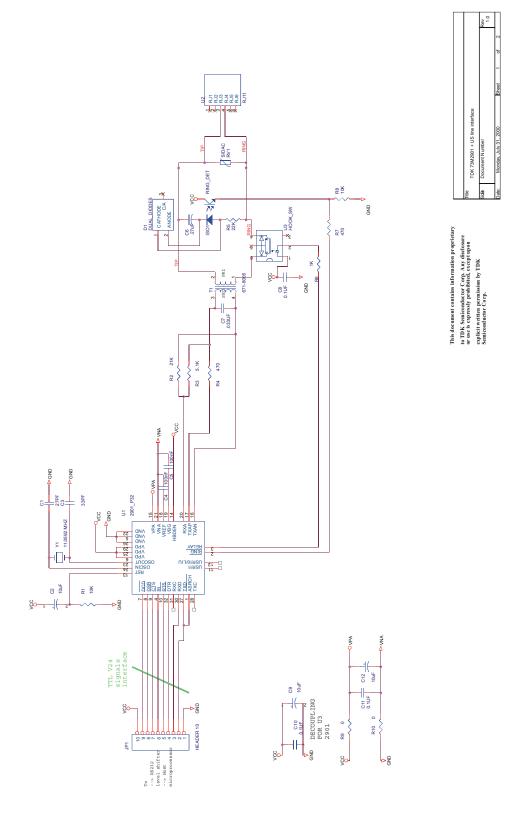


Recommended Line Interface

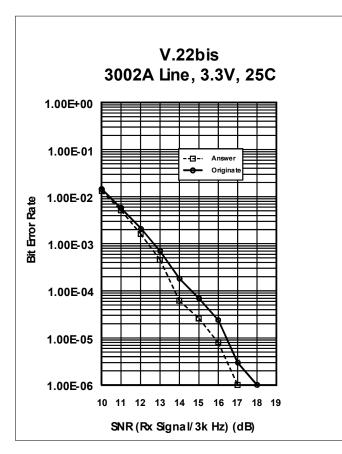


Recommended Schematics Arrangement

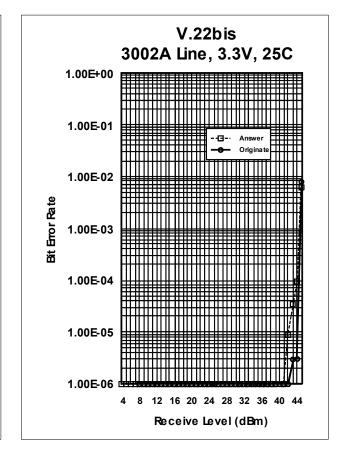
TYPICAL USA APPLICATION SCHEMATICS



BER VS SNR



BER VS RECEIVE LEVEL



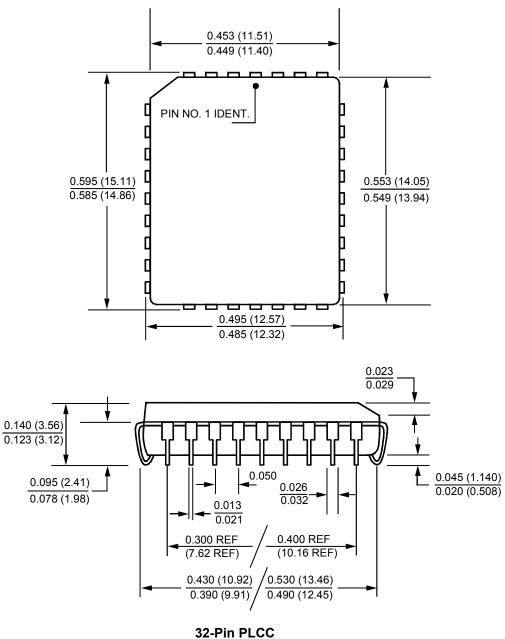
32 PIN PLCC PIN-OUT

PIN	PIN NAME	PIN	PIN NAME
1	ASRCH	17	TXAP
2	RING	18	VREF
3	RELAY	19	VBG
4	RI	20	RXA
5	VND	21	VNA
6	VPD	22	VND
7	DCD	23	OSCOUT
8	DSR	24	OSCIN
9	CTS	25	VPD
10	RTS	26	VND
11	USR11	27	TXD
12	USR10	28	TXCLK
13	RESET	29	VPD
14	HBDEN	30	RXD
15	VPA	31	RXCLK
16	TXAN	32	DTR

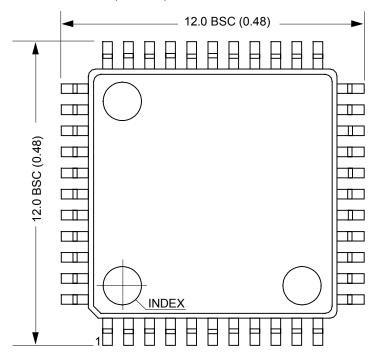
44 PIN TQFP PIN-OUT

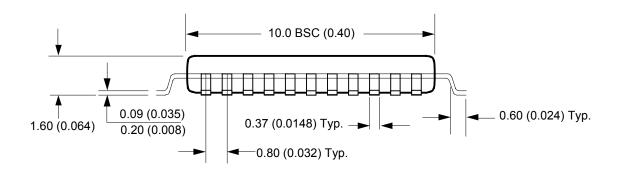
PIN	PIN NAME						
1	N/C	12	VPD	23	N/C	34	N/C
2	VPD	13	N/C	24	VND	35	RXD
3	DCD	14	N/C	25	OSCOUT	36	RXCLK
4	DSR	15	HBDEN	26	OSCIN	37	DTR
5	CTS	16	VPA	27	VPD	38	ASRCH
6	RTS	17	TXAN	28	VND	39	RING
7	USR11	18	TXAP	29	N/C	40	RELAY
8	USR10	19	VREF	30	TXD	41	N/C
9	RESET	20	VBG	31	TXCLK	42	N/C
10	N/C	21	RXA	32	N/C	43	RI
11	VND	22	VNA	33	VPD	44	VND

MECHANICAL DRAWINGS



MECHANICAL DRAWINGS (continued)





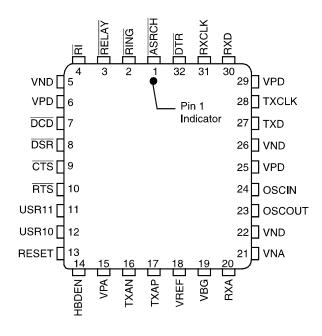
44-Pin TQFP (JEDEC LQFP)

16

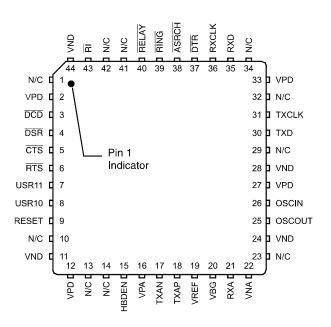
PACKAGE PIN DESIGNATIONS

(Top View)

CAUTION: Use handling procedures necessary for a static sensitive component.



32-Lead PLCC 73M2901-32IH/3



44-Pin TQFP 73M2901-IGT/3

ORDERING INFORMATION

PART DESCRIPTION	ORDER NUMBER	PACKAGING MARK	
73M2901/3.3V	73M2901-32IH/3	73M2901-32IH	
32-Pin Plastic Leaded Chip Carrier	7 3101290 1-3211 1/3		
73M2901/3.3V	73M2901-IGT/3	73M2901-IGT	
44-Pin Thin Quad Flat Pack	7 31012301-10173	7 31V1230 1-1G 1	

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